NSN 5961-01-191-3051

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-191-3051 **Inclosure Material:** Metal and glass **Overall Length:** 1.000 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 1.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 5.00 milliamperes forward current, average nanoamperes and 60.00 amperes source cutoff current **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No